

# 2MBI600VG-170E

**IGBT Modules**

## IGBT MODULE (V series) 1700V / 600A / 2 in one package

### ■ Features

- High speed switching
- Voltage drive
- Low Inductance module structure

### ■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial machines, such as Welding machines

### ■ Maximum Ratings and Characteristics

#### ● Absolute Maximum Ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Items	Symbols	Conditions	Maximum ratings	Units
Collector-Emitter voltage	$V_{CES}$		1700	V
Gate-Emitter voltage	$V_{GES}$		$\pm 20$	V
Collector current	$I_c$	Continuous	$T_c=25^\circ\text{C}$ 800 $T_c=100^\circ\text{C}$ 600	A
	$I_{CP}$	1ms	1200	
	$-I_c$		600	
	$-I_{C\ pulse}$	1ms	1200	
Collector power dissipation	$P_c$	1 device	4410	W
Junction temperature	$T_j$		175	$^\circ\text{C}$
Operating junction temperature (under switching conditions)	$T_{jop}$		150	
Storage temperature	$T_{stg}$		-40 ~ +150	
Isolation voltage	between terminal and copper base (*1) $V_{iso}$	AC : 1min.	4000	VAC
Screw torque (*2)	Mounting	-	5.75	N m
	Main Terminals	-	10	
	Sense Terminals	-	2.5	

Note \*1: All terminals should be connected together when isolation test will be done.

Note \*2: Recommendable Value :

Mounting 4.25~5.75 Nm (M6) , Main Terminals 8~10 Nm (M8) , Sense Terminals 1.7~2.5 Nm (M4)

#### ● Electrical characteristics (at $T_j=25^\circ\text{C}$ unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Zero gate voltage collector current	$I_{CES}$	$V_{GE} = 0V, V_{CE} = 1700V$	-	-	1.0	mA	
Gate-Emitter leakage current	$I_{GES}$	$V_{CE} = 0V, V_{GE} = \pm 20V$	-	-	1200	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V, I_c = 600mA$	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (main terminal)	$V_{GE} = 15V$ $I_c = 600A$	$T_j=25^\circ\text{C}$	-	2.18	2.46	V
			$T_j=125^\circ\text{C}$	-	2.58	-	
			$T_j=150^\circ\text{C}$	-	2.63	-	
	$V_{CE(sat)}$ (chip)		$T_j=25^\circ\text{C}$	-	2.00	2.25	
			$T_j=125^\circ\text{C}$	-	2.40	-	
			$T_j=150^\circ\text{C}$	-	2.45	-	
Internal gate resistance	$R_{G(int)}$		-	2.92	-	$\Omega$	
Input capacitance	$C_{ies}$	$V_{CE} = 10V, V_{GE} = 0V, f = 1MHz$	-	59	-	nF	
Turn-on	$t_{on}$	$V_{CC} = 900V, R_{gon} = 2.4\Omega$	-	2.28	-	$\mu\text{s}$	
	$t_r$	$I_c = 600A, R_{goff} = 0.82\Omega$	-	0.86	-		
Turn-off	$t_{off}$	$L_m = 75nH$	-	2.07	-		
	$t_f$	$V_{GE} = \pm 15V, T_j = 125^\circ\text{C}$	-	0.58	-		
Forward on voltage	$V_F$ (main terminal)	$V_{GE} = 0V$ $I_F = 600A$	$T_j=25^\circ\text{C}$	-	1.98	2.36	V
			$T_j=125^\circ\text{C}$	-	2.18	-	
			$T_j=150^\circ\text{C}$	-	2.16	-	
	$V_F$ (chip)		$T_j=25^\circ\text{C}$	-	1.80	2.15	
			$T_j=125^\circ\text{C}$	-	2.00	-	
			$T_j=150^\circ\text{C}$	-	1.98	-	
Reverse recovery	$t_{rr}$	$I_F = 600A, T_j = 125^\circ\text{C}$	-	0.31	-	$\mu\text{s}$	
Lead resistance, terminal-chip	R lead		-	0.291	-	m $\Omega$	

#### ● Thermal resistance characteristics

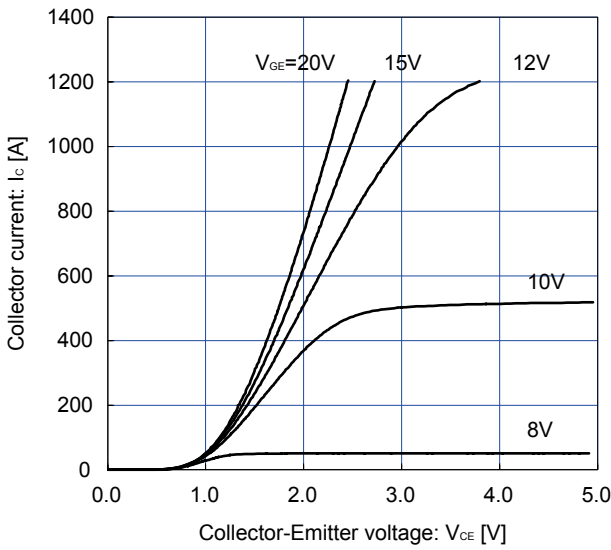
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance(1device)	$R_{th(j-c)}$	IGBT	-	-	0.034	$^\circ\text{C/W}$
		FWD	-	-	0.060	
Contact thermal resistance (1module) (*3)	$R_{th(c-f)}$	with Thermal Compound	-	0.006	-	

Note \*3: This is the value which is defined mounting on the additional cooling fin with thermal compound.

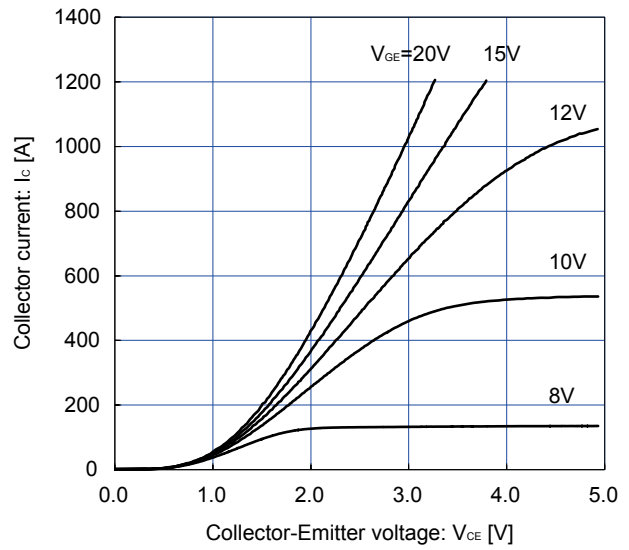


■ Characteristics (Representative)

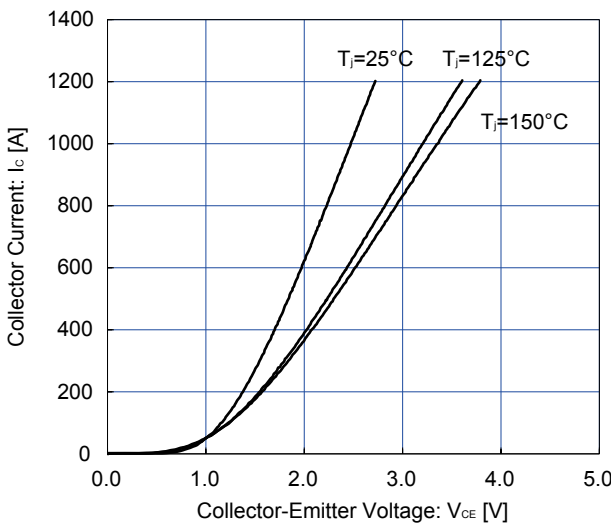
Collector current vs. Collector-Emittter voltage (typ.)  
 $T_J = 25^\circ\text{C}$ , chip



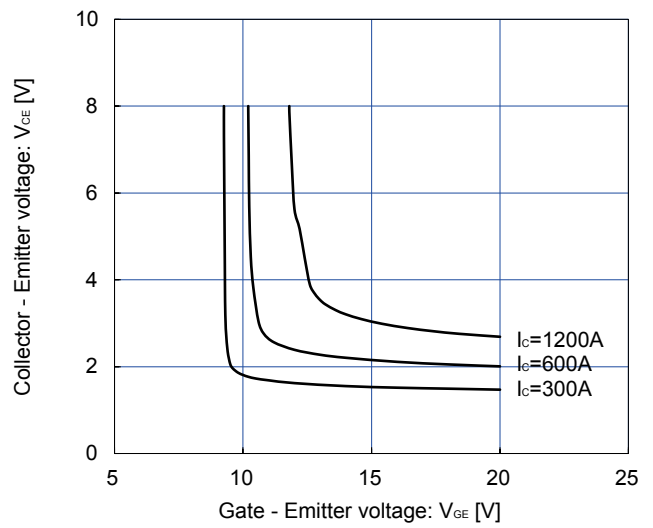
Collector current vs. Collector-Emittter voltage (typ.)  
 $T_J = 150^\circ\text{C}$ , chip



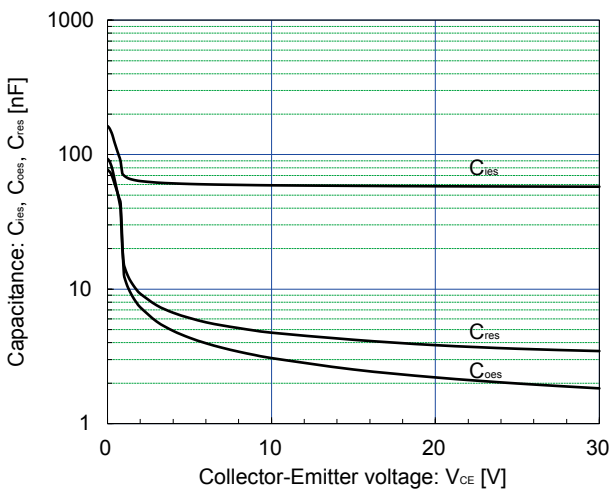
Collector current vs. Collector-Emittter voltage (typ.)  
 $V_{GE} = +15\text{V}$ , chip



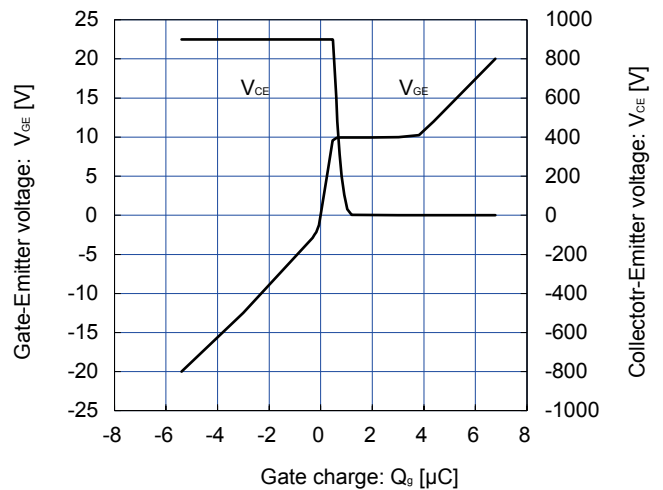
Collector-Emittter voltage vs. Gate-Emittter voltage (typ.)  
 $T_J = 25^\circ\text{C}$ , chip



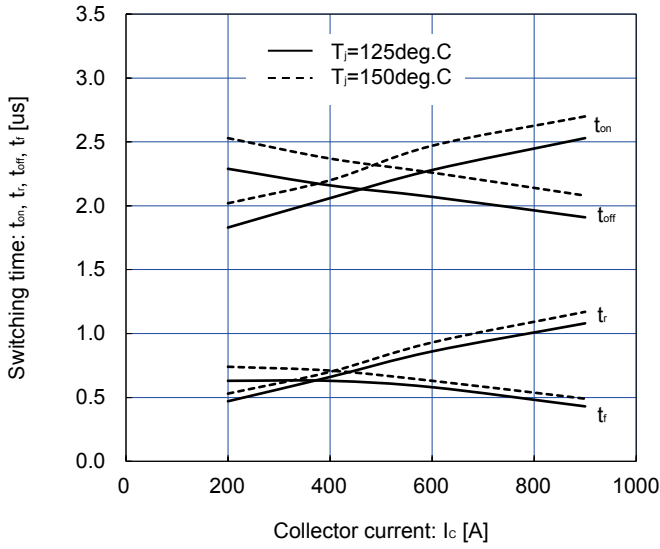
Capacitance vs. Collector-Emittter voltage (typ.)  
 $V_{GE} = 0\text{V}$ ,  $f = 1\text{MHz}$ ,  $T_J = 25^\circ\text{C}$



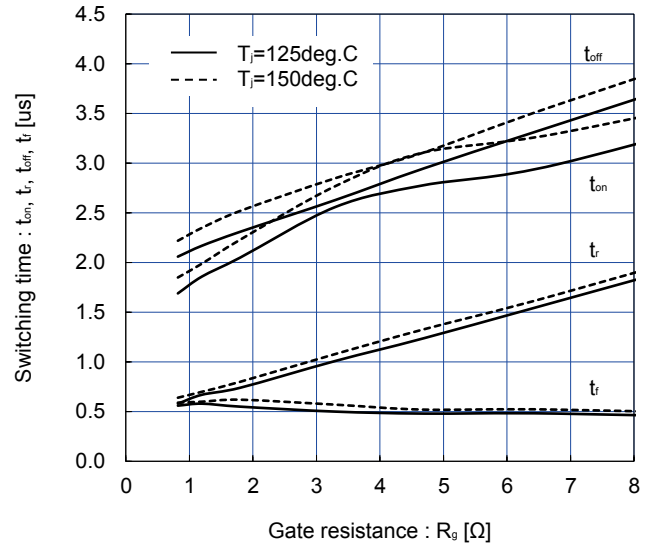
Dynamic Gate charge (typ.)  
 $T_J = 25^\circ\text{C}$



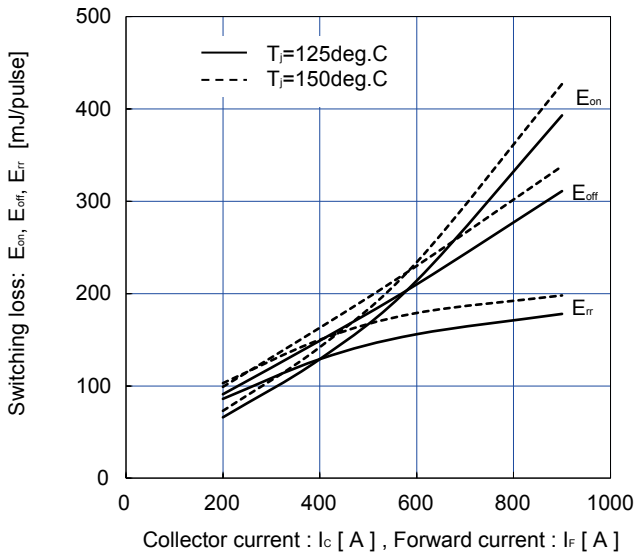
Switching time vs. Collector current (typ.)  
 $V_{CC}=900V, V_{GE}=\pm 15V, R_{gon}=2.4\Omega, R_{goff}=0.82\Omega$



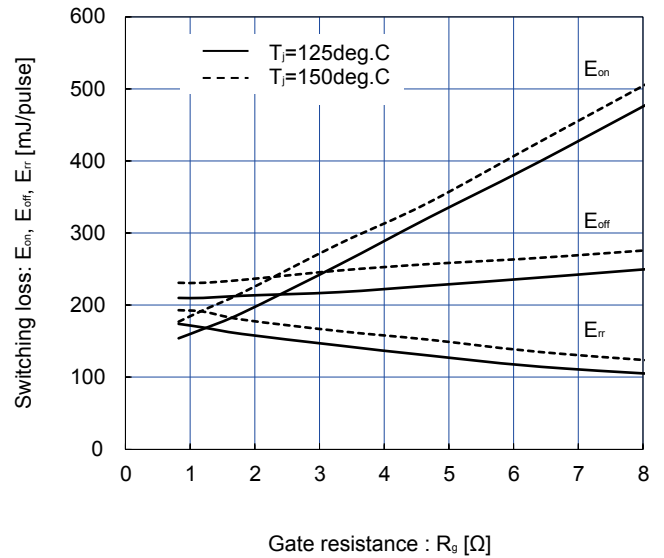
Switching time vs. Gate resistance (typ.)  
 $V_{CC}=900V, V_C=600A, V_{GE}=\pm 15V$



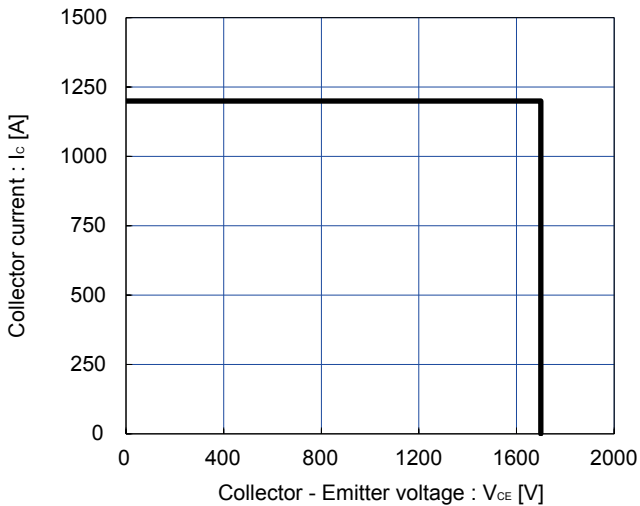
Switching loss vs. Collector current (typ.)  
 $V_{CC}=900V, V_{GE}=\pm 15V, R_{gon}=2.4\Omega, R_{goff}=0.82\Omega$



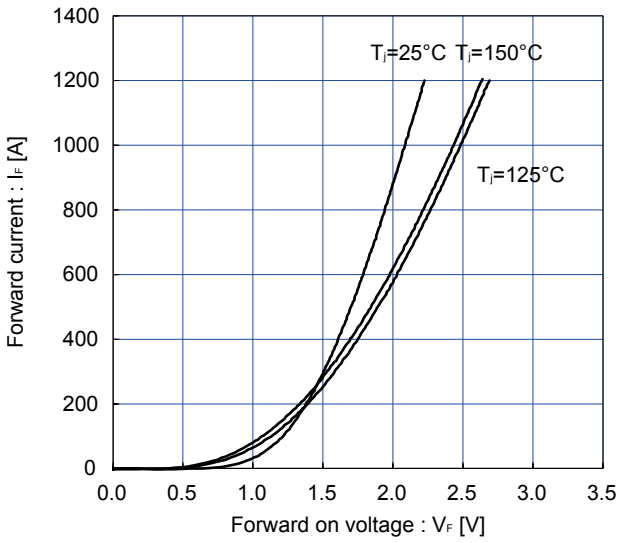
Switching loss vs. Gate resistance (typ.)  
 $V_{CC}=900V, I_C=600A, V_{GE}=\pm 15V$



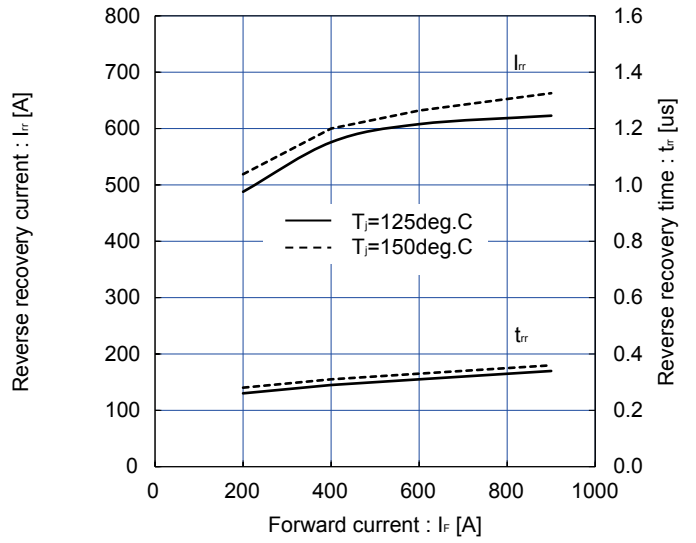
Reverse bias safe operating area (max.)  
 $\pm V_{GE}=15V, T_j=150^\circ C / \text{chip}$



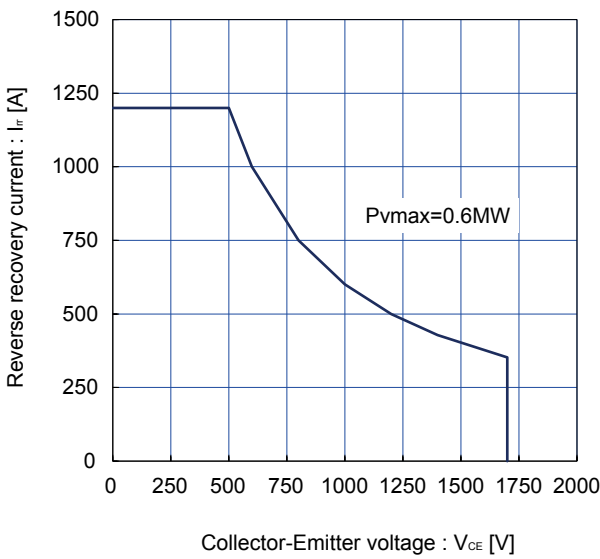
Forward current vs. Forward on voltage (typ.)  
chip



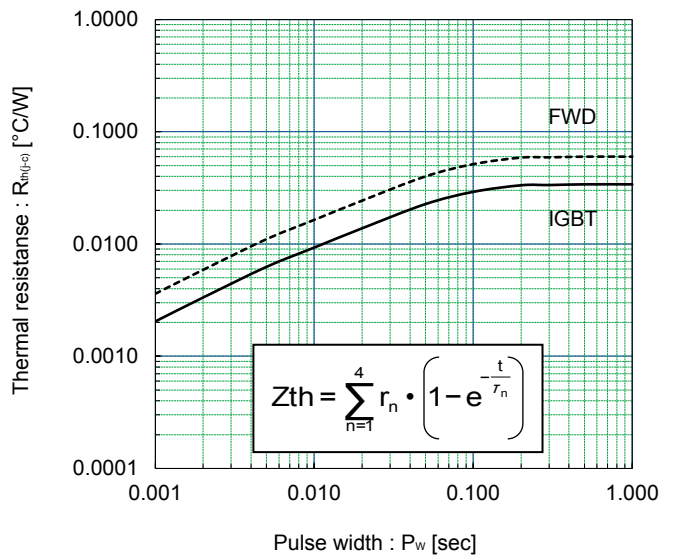
Reverse recovery characteristics (typ.)  
V<sub>CC</sub>=900V, V<sub>GE</sub>=±15V, R<sub>gon</sub>=2.4Ω



FWD safe operating area (max.)  
T<sub>J</sub>=150°C / sence terminals

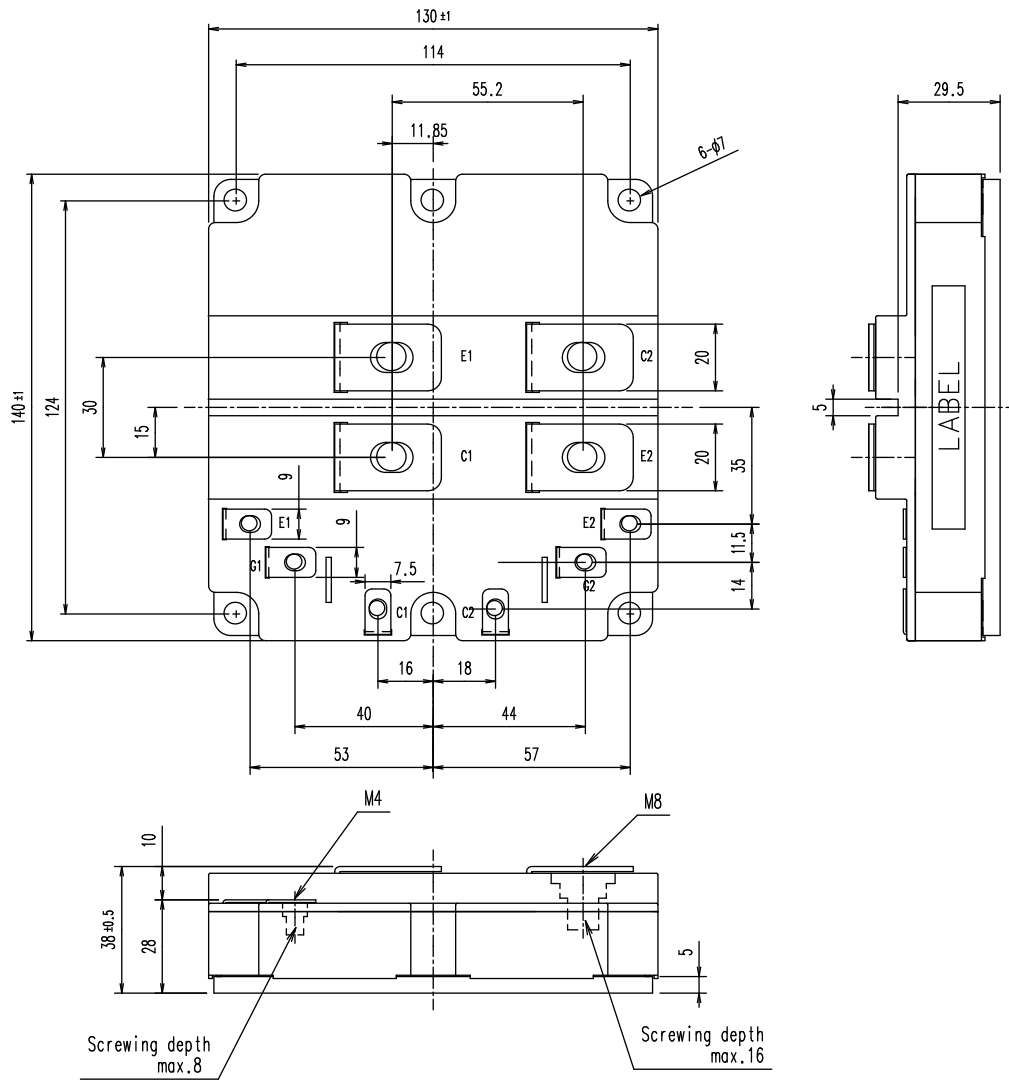


Transient thermal resistance (max.)

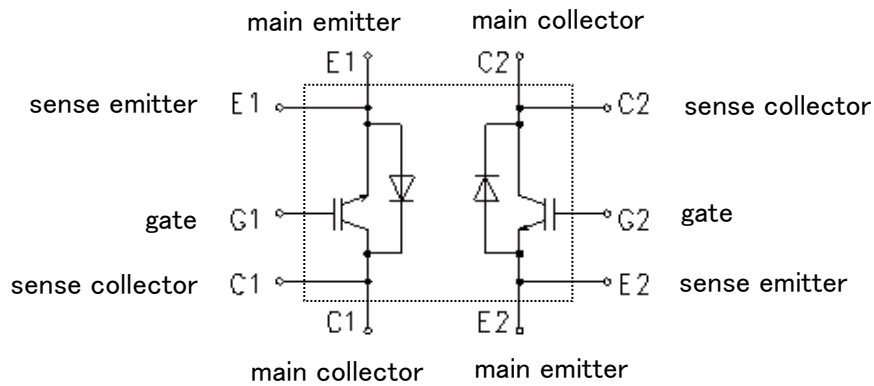


	IGBT	FWD
r1	0.00383	0.00667
r1	0.01312	0.02317
r3	0.00941	0.01659
r4	0.00764	0.01356
t1	0.0024	0.0024
t2	0.0359	0.0355
t3	0.0627	0.0638
t4	0.0743	0.0733

■ Outline Drawing (Unit : mm)



■ Equivalent circuit



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